

FEATURES

- 1.5 Ω on resistance
- 0.3 Ω on-resistance flatness
- 0.1 Ω on-resistance match between channels
- Up to 400 mA continuous current
- Fully specified at +12 V, ± 15 V, and ± 5 V
- No V_L supply required
- 3 V logic-compatible inputs
- Rail-to-rail operation
- 14-lead TSSOP and 4 mm \times 4 mm, 16-lead LFCSP

APPLICATIONS

- Automatic test equipment
- Data acquisition systems
- Battery-powered systems
- Sample-and-hold systems
- Audio signal routing
- Communication systems
- Relay replacement

GENERAL DESCRIPTION

The ADG1404 is a complementary metal-oxide semiconductor (CMOS) analog multiplexer, comprising four single channels designed on an *i*CMOS[®] process. *i*CMOS (industrial CMOS) is a modular manufacturing process that combines high voltage CMOS and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of 33 V operation in a footprint that no previous generation of high voltage parts has been able to achieve. Unlike analog ICs using conventional CMOS processes, *i*CMOS components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.

The on-resistance profile is very flat over the full analog input range, ensuring excellent linearity and low distortion when switching audio signals.

*i*CMOS construction ensures ultralow power dissipation, making the parts ideally suited for portable and battery-powered instruments.

FUNCTIONAL BLOCK DIAGRAM

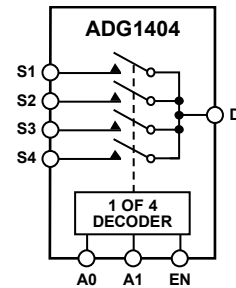


Figure 1.

The ADG1404 switches one of four inputs to a common output, D, as determined by the 3-bit binary address lines, A0, A1, and EN. Logic 0 on the EN pin disables the device. Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked. All switches exhibit break-before-make switching action. Inherent in the design is low charge injection for minimum transients when switching the digital inputs.

PRODUCT HIGHLIGHTS

1. 2.6 Ω maximum on resistance over temperature.
2. Minimum distortion.
3. Ultralow power dissipation: $<0.03 \mu\text{W}$.
4. 14-lead TSSOP and 16-lead, 4 mm \times 4 mm LFCSP package.

Rev. A

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REVISION HISTORY

3/09—Rev. 0 to Rev. A

| | |
|---|----|
| Changes to Power Requirements, I_{DD} , Digital Inputs = 5 V Parameter, Table 1..... | 3 |
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| Updated Outline Dimensions | 16 |

7/08—Revision 0: Initial Version

SPECIFICATIONS

15 V DUAL SUPPLY

$V_{DD} = 15\text{ V} \pm 10\%$, $V_{SS} = -15\text{ V} \pm 10\%$, $GND = 0\text{ V}$, unless otherwise noted.

Table 1.

| Parameter | 25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|---|------------|----------------|----------------------|-------------------|---|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | V_{DD} to V_{SS} | V | |
| On Resistance (R_{ON}) | 1.5 | | | Ω typ | $V_S = \pm 10\text{ V}$, $I_S = -10\text{ mA}$; see Figure 22 |
| | 1.8 | 2.3 | 2.6 | Ω max | $V_{DD} = +13.5\text{ V}$, $V_{SS} = -13.5\text{ V}$ |
| On-Resistance Match Between Channels (ΔR_{ON}) | 0.1 | | | Ω typ | $V_S = \pm 10\text{ V}$, $I_S = -10\text{ mA}$ |
| | 0.18 | 0.19 | 0.21 | Ω max | |
| On-Resistance Flatness ($R_{FLAT(ON)}$) | 0.3 | | | Ω typ | $V_S = \pm 10\text{ V}$, $I_S = -10\text{ mA}$ |
| | 0.36 | 0.4 | 0.45 | Ω max | |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage, I_S (Off) | ± 0.03 | | | nA typ | $V_{DD} = +16.5\text{ V}$, $V_{SS} = -16.5\text{ V}$ |
| | ± 0.55 | ± 2 | ± 12.5 | nA max | $V_S = \pm 10\text{ V}$, $V_S = \mp 10\text{ V}$; see Figure 23 |
| Drain Off Leakage, I_D (Off) | ± 0.04 | | | nA typ | |
| | ± 0.55 | ± 4 | ± 30 | nA max | $V_S = \pm 10\text{ V}$, $V_S = \mp 10\text{ V}$; see Figure 23 |
| Channel On Leakage, I_D , I_S (On) | ± 0.1 | | | nA typ | $V_S = V_D = \pm 10\text{ V}$; see Figure 24 |
| | ± 2 | ± 4 | ± 30 | nA max | |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | 2.0 | V min | |
| Input Low Voltage, V_{INL} | | | 0.8 | V max | |
| Input Current, I_{INL} or I_{INH} | 0.005 | | | μA typ | $V_{IN} = V_{GND}$ or V_{DD} |
| | | | ± 0.1 | μA max | |
| Digital Input Capacitance, C_{IN} | 3.5 | | | pF typ | |
| DYNAMIC CHARACTERISTICS¹ | | | | | |
| Transition Time, $t_{TRANSITION}$ | 150 | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | 180 | 220 | 250 | ns max | $V_S = +10\text{ V}$; see Figure 29 |
| t_{ON} (EN) | 100 | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | 120 | 145 | 165 | ns max | $V_S = +10\text{ V}$; see Figure 31 |
| t_{OFF} (EN) | 110 | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | 135 | 165 | 185 | ns max | $V_S = +10\text{ V}$; see Figure 31 |
| Break-Before-Make Time Delay, t_{BBM} | 35 | | 10 | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | | | | ns min | $V_{S1} = V_{S2} = 10\text{ V}$; see Figure 30 |
| Charge Injection | -20 | | | pC typ | $V_S = 0\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; see Figure 32 |
| Off Isolation | 70 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; see Figure 25 |
| Channel-to-Channel Crosstalk | 82 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; see Figure 27 |
| Total Harmonic Distortion + Noise | 0.011 | | | % typ | $R_L = 110\ \Omega$, 10 V p-p, $f = 20\text{ Hz}$ to 20 kHz; see Figure 28 |
| -3 dB Bandwidth | 55 | | | MHz typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; see Figure 26 |
| Insertion Loss | -0.17 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 26 |
| C_S (Off) | 23 | | | pF typ | $f = 1\text{ MHz}$, $V_S = 0\text{ V}$ |
| C_D (Off) | 90 | | | pF typ | $f = 1\text{ MHz}$, $V_S = 0\text{ V}$ |
| C_D , C_S (On) | 170 | | | pF typ | $f = 1\text{ MHz}$, $V_S = 0\text{ V}$ |
| POWER REQUIREMENTS | | | | | |
| I_{DD} | 0.001 | | | μA typ | $V_{DD} = +16.5\text{ V}$, $V_{SS} = -16.5\text{ V}$ |
| | | | 1 | μA max | Digital inputs = 0 V or V_{DD} |
| I_{DD} | 170 | | | μA typ | Digital inputs = 5 V |
| | | | 285 | μA max | |
| I_{SS} | 0.001 | | | μA typ | Digital inputs = 0 V or V_{DD} |
| | | | 1 | μA max | |
| V_{DD}/V_{SS} | | | $\pm 4.5/\pm 16.5$ | V min/max | $GND = 0\text{ V}$ |

¹ Guaranteed by design, not subject to production test.

ADG1404

12 V SINGLE SUPPLY

$V_{DD} = 12\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 2.

| Parameter | 25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|---|--------------------------|----------------|-----------------|--|---|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | 0 V to V_{DD} | V | |
| On Resistance (R_{ON}) | 2.8 3.5 | 4.3 | 4.8 | Ω typ Ω max | $V_S = 0\text{ V to }10\text{ V}$, $I_S = -10\text{ mA}$; see Figure 22 $V_{DD} = 10.8\text{ V}$, $V_{SS} = 0\text{ V}$ |
| On-Resistance Match Between Channels (ΔR_{ON}) | 0.13 | | | Ω typ | $V_S = 0\text{ V to }10\text{ V}$, $I_S = -10\text{ mA}$ |
| On-Resistance Flatness ($R_{FLAT(ON)}$) | 0.21 0.6 | 0.23 | 0.25 | Ω max Ω typ | $V_S = 0\text{ V to }10\text{ V}$, $I_S = -10\text{ mA}$ |
| | 1.1 | 1.2 | 1.3 | Ω max | |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage, I_S (Off) | ± 0.02 ± 0.55 | ± 2 | ± 12.5 | nA typ nA max | $V_{DD} = 13.2\text{ V}$, $V_{SS} = 0\text{ V}$ $V_S = 1\text{ V}/10\text{ V}$, $V_D = 10\text{ V}/1\text{ V}$; see Figure 23 |
| Drain Off Leakage, I_D (Off) | ± 0.03 ± 0.55 | ± 4 | ± 30 | nA typ nA max | $V_S = 1\text{ V}/10\text{ V}$, $V_D = 10\text{ V}/1\text{ V}$; see Figure 23 |
| Channel On Leakage, I_D , I_S (On) | ± 0.1 ± 1.5 | ± 4 | ± 30 | nA typ nA max | $V_S = V_D = 1\text{ V or }10\text{ V}$; see Figure 24 |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | 2.0 | V min | |
| Input Low Voltage, V_{INL} | | | 0.8 | V max | |
| Input Current, I_{INL} or I_{INH} | 0.001 | | ± 0.1 | μA typ μA max | $V_{IN} = V_{GND}$ or V_{DD} |
| Digital Input Capacitance, C_{IN} | 3.5 | | | pF typ | |
| DYNAMIC CHARACTERISTICS¹ | | | | | |
| Transition Time, $t_{TRANSITION}$ | 230 300 | 375 | 430 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = 8\text{ V}$; see Figure 29 |
| t_{ON} (EN) | 180 240 | 295 | 335 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = 8\text{ V}$; see Figure 31 |
| t_{OFF} (EN) | 115 160 | 190 | 220 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = 8\text{ V}$; see Figure 31 |
| Break-Before-Make Time Delay, t_{BBM} | 100 | | 10 | ns typ ns min | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_{S1} = V_{S2} = 8\text{ V}$; see Figure 30 |
| Charge Injection | 30 | | | pC typ | $V_S = 6\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; see Figure 32 |
| Off Isolation | 80 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; see Figure 25 |
| Channel-to-Channel Crosstalk | 82 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; see Figure 27 |
| -3 dB Bandwidth | 35 | | | MHz typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; see Figure 26 |
| Insertion Loss | -0.3 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 26 |
| C_S (Off) | 39 | | | pF typ | $f = 1\text{ MHz}$, $V_S = 6\text{ V}$ |
| C_D (Off) | 150 | | | pF typ | $f = 1\text{ MHz}$, $V_S = 6\text{ V}$ |
| C_D , C_S (On) | 217 | | | pF typ | $f = 1\text{ MHz}$, $V_S = 6\text{ V}$ |
| POWER REQUIREMENTS | | | | | |
| I_{DD} | 0.001 | | 1 | μA typ μA max | $V_{DD} = 13.2\text{ V}$ Digital inputs = 0 V or V_{DD} |
| I_{DD} | 170 | | 285 | μA typ μA max | Digital inputs = 5 V |
| V_{DD} | | | 5/16.5 | V min/max | $GND = 0\text{ V}$, $V_{SS} = 0\text{ V}$ |

¹ Guaranteed by design, not subject to production test.

5 V DUAL SUPPLY

$V_{DD} = 5\text{ V} \pm 10\%$, $V_{SS} = -5\text{ V} \pm 10\%$, $GND = 0\text{ V}$, unless otherwise noted.

Table 3.

| Parameter | 25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|---|--|----------------|----------------------|--|--|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | V_{DD} to V_{SS} | V | |
| On Resistance (R_{ON}) | 3.3 4 | 4.9 | 5.4 | Ω typ Ω max | $V_S = \pm 4.5\text{ V}$, $I_S = -10\text{ mA}$; see Figure 22 $V_{DD} = +4.5\text{ V}$, $V_{SS} = -4.5\text{ V}$ |
| On-Resistance Match Between Channels (ΔR_{ON}) | 0.13 | | | Ω typ | $V_S = \pm 4.5\text{ V}$, $I_S = -10\text{ mA}$ |
| On-Resistance Flatness ($R_{FLAT(ON)}$) | 0.22 0.9 1.1 | 0.23 | 0.25 1.31 | Ω max Ω typ Ω max | $V_S = \pm 4.5\text{ V}$, $I_S = -10\text{ mA}$ |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage, I_S (Off) | ± 0.02 | | | nA typ | $V_{DD} = +5.5\text{ V}$, $V_{SS} = -5.5\text{ V}$ $V_S = \pm 4.5\text{ V}$, $V_D = \mp 4.5\text{ V}$; see Figure 23 |
| Drain Off Leakage, I_D (Off) | ± 0.2 ± 0.02 | ± 1 | ± 12.5 | nA max nA typ | $V_S = \pm 4.5\text{ V}$, $V_D = \mp 4.5\text{ V}$; see Figure 23 |
| Channel On Leakage, I_D , I_S (On) | ± 0.25 ± 0.05 ± 0.25 | ± 1.2 | ± 15 ± 20 | nA max nA typ nA max | $V_S = V_D = \pm 4.5\text{ V}$; see Figure 24 |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | 2.0 | V min | |
| Input Low Voltage, V_{INL} | | | 0.8 | V max | |
| Input Current, I_{INL} or I_{INH} | 0.001 | | ± 0.1 | μA typ μA max | $V_{IN} = V_{GND}$ or V_{DD} |
| Digital Input Capacitance, C_{IN} | 3.5 | | | pF typ | |
| DYNAMIC CHARACTERISTICS¹ | | | | | |
| Transition Time, $t_{TRANSITION}$ | 340 470 | 560 | 615 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = 3\text{ V}$; Figure 29 |
| t_{ON} (EN) | 260 355 | 430 | 480 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = 3\text{ V}$; Figure 31 |
| t_{OFF} (EN) | 220 315 | 365 | 400 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = 3\text{ V}$; Figure 31 |
| Break-Before-Make Time Delay, t_{BBM} | 100 | | 50 | ns typ ns min | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_{S1} = V_{S2} = 3\text{ V}$; see Figure 30 |
| Charge Injection | 30 | | | pC typ | $V_S = 0\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; see Figure 32 |
| Off Isolation | 80 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; see Figure 25 |
| Channel-to-Channel Crosstalk | 82 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; see Figure 27 |
| -3 dB Bandwidth | 40 | | | MHz typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; see Figure 26 |
| Insertion Loss | 0.27 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 26 |
| Total Harmonic Distortion + Noise | 0.03 | | | % typ | $R_L = 110\ \Omega$, 2.5 V p-p, $f = 20\text{ Hz}$ to 20 kHz; see Figure 28 |
| C_S (Off) | 33 | | | pF typ | $V_S = 0\text{ V}$, $f = 1\text{ MHz}$ |
| C_D (Off) | 128 | | | pF typ | $V_S = 0\text{ V}$, $f = 1\text{ MHz}$ |
| C_D , C_S (On) | 210 | | | pF typ | $V_S = 0\text{ V}$, $f = 1\text{ MHz}$ |
| POWER REQUIREMENTS | | | | | |
| I_{DD} | 0.001 | | 1 | μA typ μA max | $V_{DD} = 5.5\text{ V}$, $V_{SS} = -5.5\text{ V}$ Digital inputs = 0 V, 5 V, or V_{DD} |
| I_{SS} | 0.001 | | 1 | μA typ μA max | Digital inputs = 0 V or V_{DD} |
| V_{DD}/V_{SS} | | | $\pm 4.5/\pm 16.5$ | V min/max | $GND = 0\text{ V}$ |

¹ Guaranteed by design, not subject to production test.

ADG1404

CONTINUOUS CURRENT, S OR D

Table 4.

| Parameter | 25°C | 85°C | 125°C | Unit | Test Conditions/Comments |
|---|------|------|-------|--------|--|
| CONTINUOUS CURRENT, S or D ¹ | | | | | |
| 15 V Dual Supply | | | | | $V_{DD} = +13.5\text{ V}, V_{SS} = -13.5\text{ V}$ |
| ADG1404 TSSOP | 350 | 220 | 100 | mA max | |
| ADG1404 LFCSP | 450 | 300 | 140 | mA max | |
| 12 V Single Supply | | | | | $V_{DD} = 10.8\text{ V}, V_{SS} = 0\text{ V}$ |
| ADG1404 TSSOP | 300 | 220 | 100 | mA max | |
| ADG1404 LFCSP | 400 | 300 | 140 | mA max | |
| 5 V Dual Supply | | | | | $V_{DD} = +4.5\text{ V}, V_{SS} = -4.5\text{ V}$ |
| ADG1404 TSSOP | 300 | 220 | 100 | mA max | |
| ADG1404 LFCSP | 400 | 300 | 140 | mA max | |

¹ Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 5.

| Parameter | Rating |
|--|---|
| V_{DD} to V_{SS} | 35 V |
| V_{DD} to GND | -0.3 V to +25 V |
| V_{SS} to GND | +0.3 V to -25 V |
| Analog Inputs ¹ | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first |
| Digital Inputs | GND - 0.3 V to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first |
| Peak Current, S or D | 600 mA (pulsed at 1 ms, 10% duty cycle maximum) |
| Continuous Current, S or D ² | Data + 15% |
| Operating Temperature Range Automotive (Y Version) | -40°C to +125°C |
| Storage Temperature Range | -65°C to +150°C |
| Junction Temperature | 150°C |
| 14-Lead TSSOP, θ_{JA} Thermal Impedance (4-layer board) | 112°C/W |
| 16-Lead LFCSOP, θ_{JA} Thermal Impedance | 30.4°C/W |
| Reflow Soldering Peak Temperature, Pb free | 260(+0/-5)°C |

¹ Overvoltages at IN, S, and D are clamped by internal diodes. Current should be limited to the maximum ratings given.

² See data given in Table 4.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating may be applied at any one time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

ADG1404

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

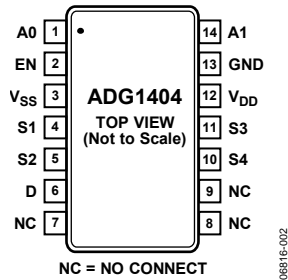
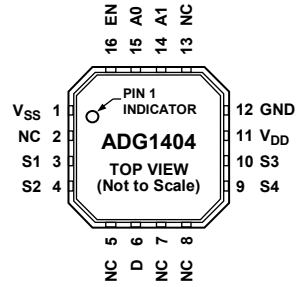


Figure 2. TSSOP Pin Configuration



NOTES
1. EXPOSED PAD TIED TO SUBSTRATE, V_{SS} .
2. NC = NO CONNECT.

Figure 3. LFCSP Pin Configuration

Table 6. Pin Function Descriptions

| Pin No. | | Mnemonic | Description |
|---------|----------------|----------|---|
| TSSOP | LFCSP | | |
| 1 | 15 | A0 | Logic Control Input. |
| 2 | 16 | EN | Active High Digital Input. When this pin is low, the device is disabled and all switches are off. When this pin is high, the Ax logic inputs determine the on switches. |
| 3 | 1 | V_{SS} | Most Negative Power Supply Potential. |
| 4 | 3 | S1 | Source Terminal. Can be an input or an output. |
| 5 | 4 | S2 | Source Terminal. Can be an input or an output. |
| 6 | 6 | D | Drain Terminal. Can be an input or an output. |
| 7 to 9 | 2, 5, 7, 8, 13 | NC | No Connection. |
| 10 | 9 | S4 | Source Terminal. Can be an input or an output. |
| 11 | 10 | S3 | Source Terminal. Can be an input or an output. |
| 12 | 11 | V_{DD} | Most Positive Power Supply Potential. |
| 13 | 12 | GND | Ground (0 V) Reference. |
| 14 | 14 | A1 | Logic Control Input. |

TRUTH TABLE

Table 7.

| EN | A1 | A0 | S1 | S2 | S3 | S4 |
|----|----|----|-----|-----|-----|-----|
| 0 | X | X | Off | Off | Off | Off |
| 1 | 0 | 0 | On | Off | Off | Off |
| 1 | 0 | 1 | Off | On | Off | Off |
| 1 | 1 | 0 | Off | Off | On | Off |
| 1 | 1 | 1 | Off | Off | Off | On |

TYPICAL PERFORMANCE CHARACTERISTICS

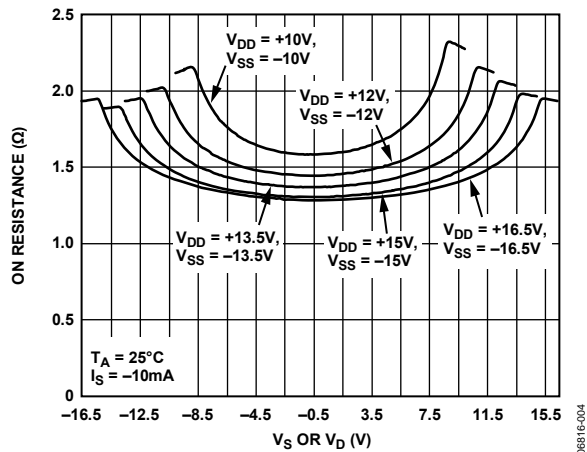


Figure 4. On Resistance as a Function of V_D (V_S), Dual Supply

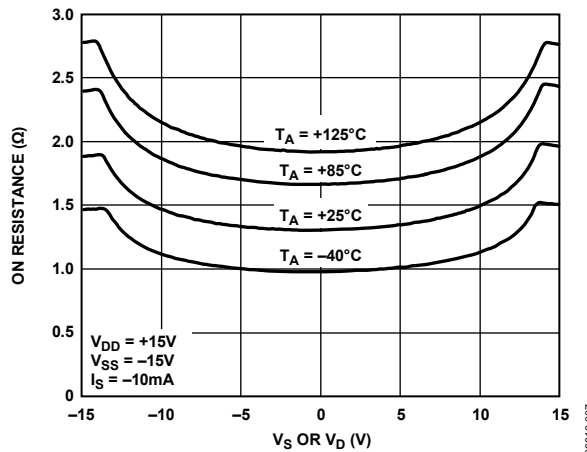


Figure 7. On Resistance as a Function of V_D (V_S) for Different Temperatures, 15 V Dual Supply

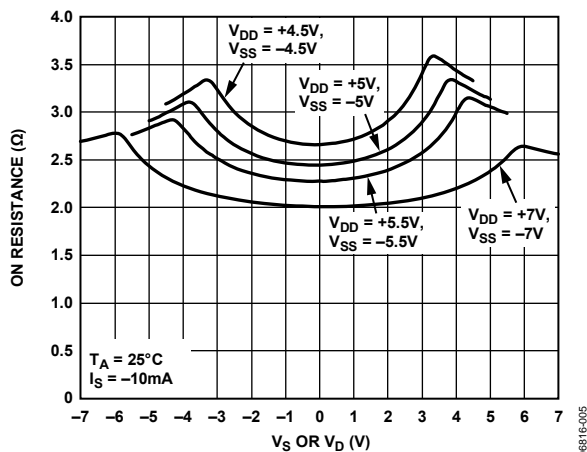


Figure 5. On Resistance as a Function of V_D (V_S), Dual Supply

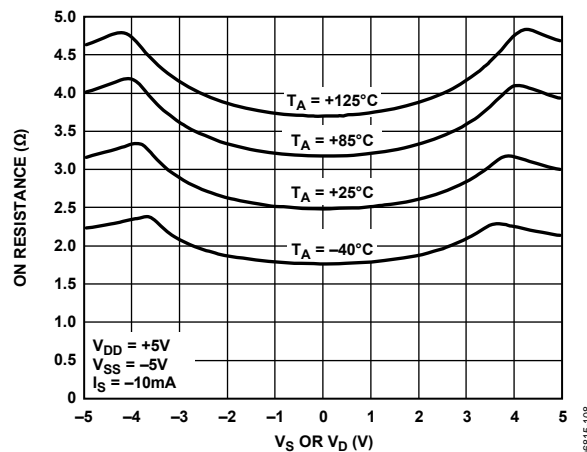


Figure 8. On Resistance as a Function of V_D (V_S) for Different Temperatures, 5 V Dual Supply

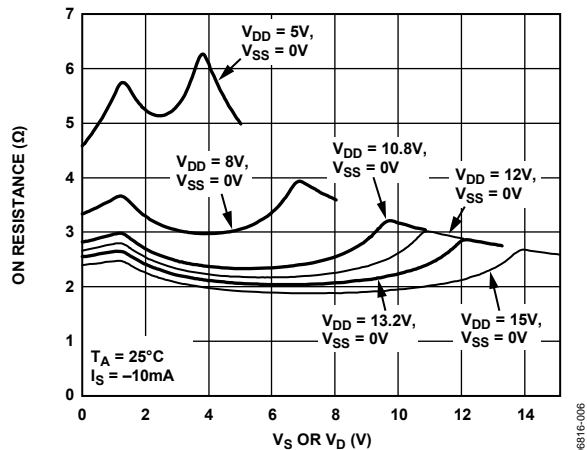


Figure 6. On Resistance as a Function of V_D (V_S), Single Supply

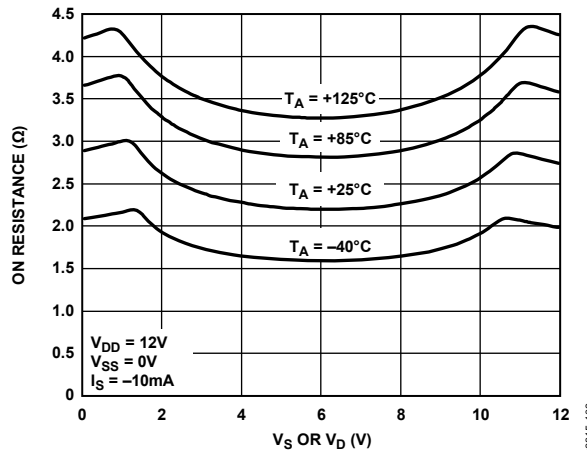


Figure 9. On Resistance as a Function of V_D (V_S) for Different Temperatures, Single Supply

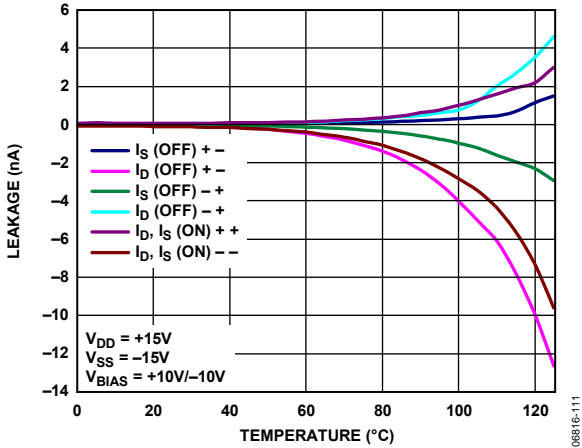


Figure 10. Leakage Currents as a Function of Temperature, 15 V Dual Supply

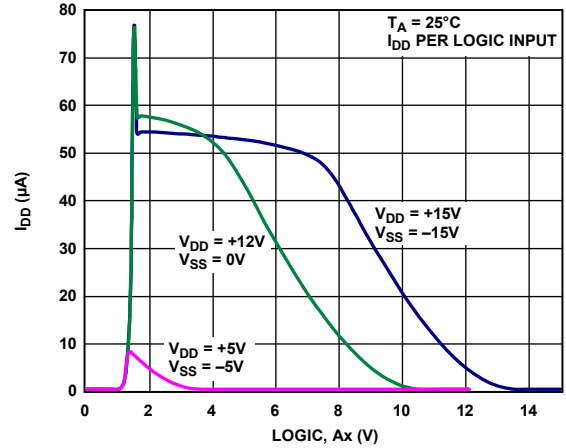


Figure 13. I_{DD} vs. Logic Level

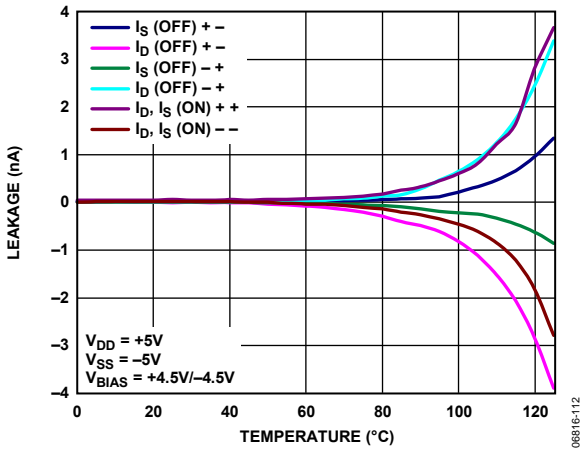


Figure 11. Leakage Currents as a Function of Temperature, 5 V Dual Supply

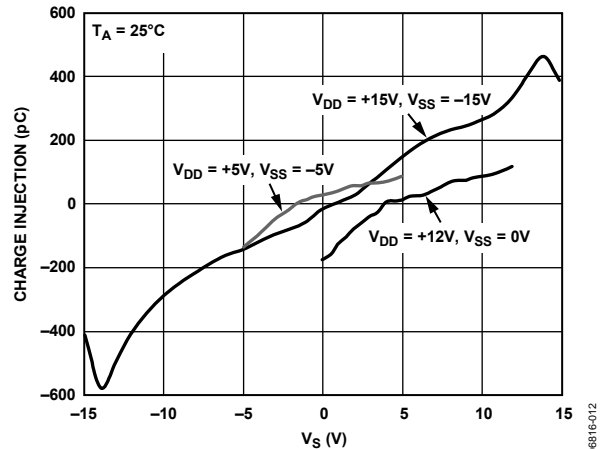


Figure 14. Charge Injection vs. Source Voltage

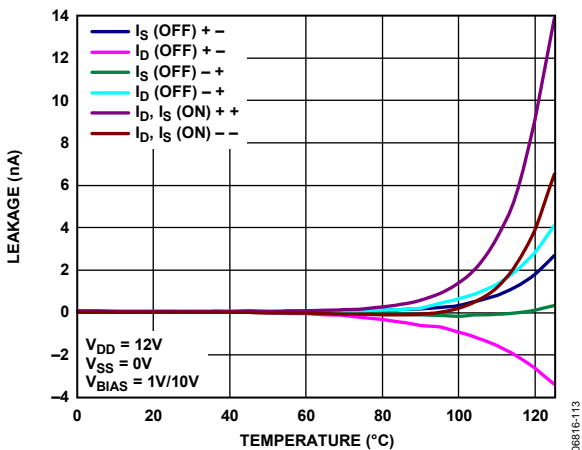


Figure 12. Leakage Currents as a Function of Temperature, 12 V Single Supply

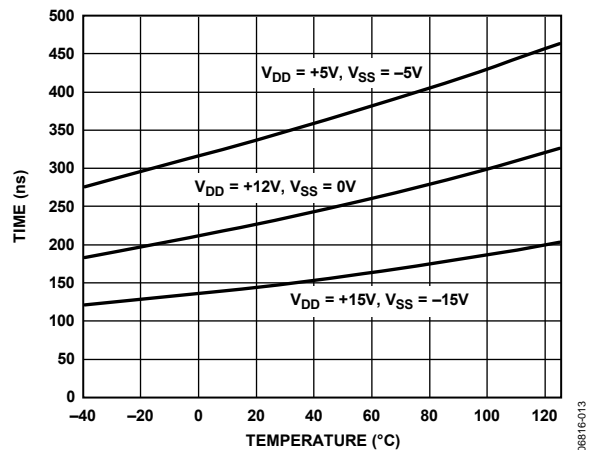


Figure 15. Transition Times vs. Temperature

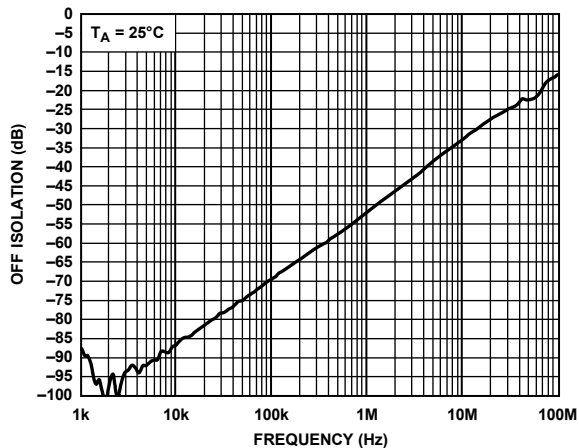


Figure 16. Off Isolation vs. Frequency

06816-014

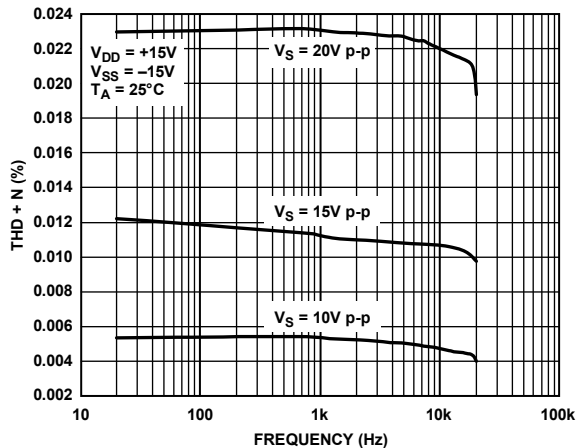


Figure 19. THD + N vs. Frequency at ± 15 V

06816-017

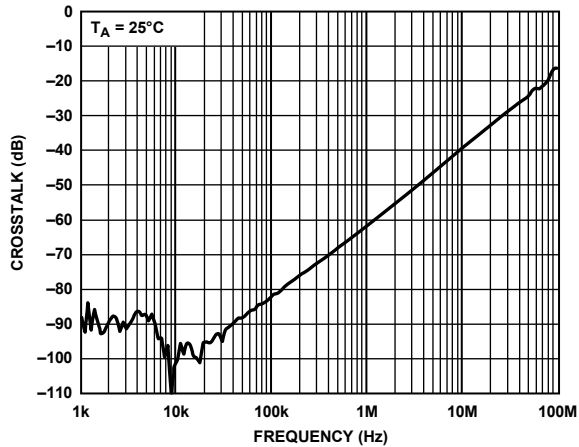


Figure 17. Crosstalk vs. Frequency

06816-015

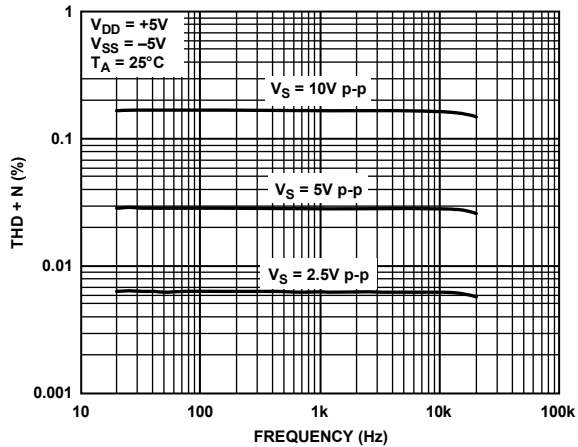


Figure 20. THD + N vs. Frequency at ± 5 V

06816-018

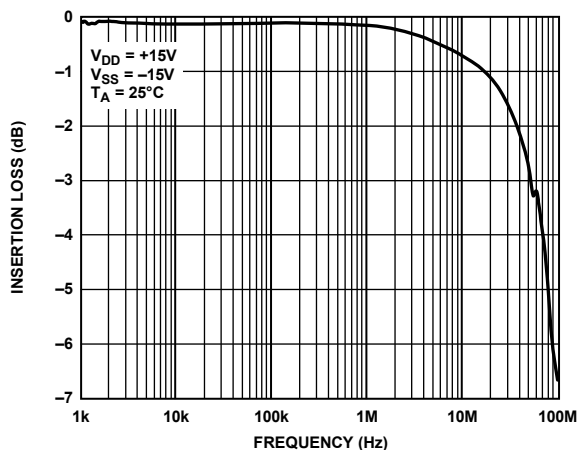


Figure 18. On Response vs. Frequency

06816-016

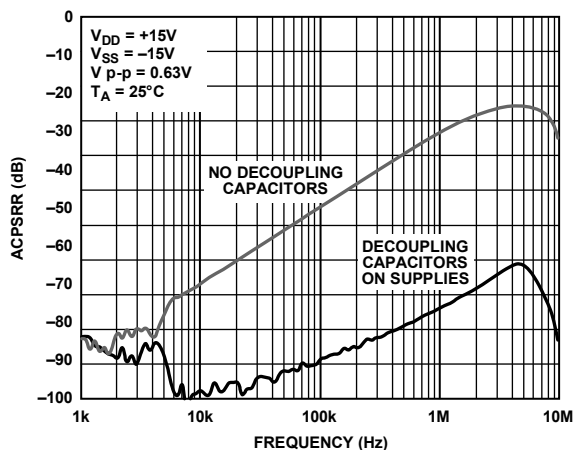


Figure 21. ACPSRR vs. Frequency

06815-017

TERMINOLOGY

I_{DD}

The positive supply current.

I_{SS}

The negative supply current.

V_D (V_S)

The analog voltage on Terminal D and Terminal S.

R_{ON}

The ohmic resistance between Terminal D and Terminal S.

R_{FLAT(ON)}

Flatness that is defined as the difference between the maximum and minimum value of on resistance measured over the specified analog signal range.

I_S (Off)

The source leakage current with the switch off.

I_D (Off)

The drain leakage current with the switch off.

I_D, I_S (On)

The channel leakage current with the switch on.

V_{INL}

The maximum input voltage for Logic 0.

V_{INH}

The minimum input voltage for Logic 1.

I_{INL} (I_{INH})

The input current of the digital input.

C_S (Off)

The off switch source capacitance, which is measured with reference to ground.

C_D (Off)

The off switch drain capacitance, which is measured with reference to ground.

C_D, C_S (On)

The on switch capacitance, which is measured with reference to ground.

C_{IN}

The digital input capacitance.

t_{TRANSITION}

The delay time between the 50% and 90% points of the digital input and switch on condition when switching from one address state to another.

t_{ON} (EN)

The delay between applying the digital control input and the output switching on. See Figure 29, Test Circuit 4.

t_{OFF} (EN)

The delay between applying the digital control input and the output switching off.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Off Isolation

A measure of unwanted signal coupling through an off switch.

Crosstalk

A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

Bandwidth

The frequency at which the output is attenuated by 3 dB.

On Response

The frequency response of the on switch.

Insertion Loss

The loss due to the on resistance of the switch.

THD + N

The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

ACPSRR (AC Power Supply Rejection Ratio)

The ratio of the amplitude of signal on the output to the amplitude of the modulation. This is a measure of the part's ability to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p.

TEST CIRCUITS

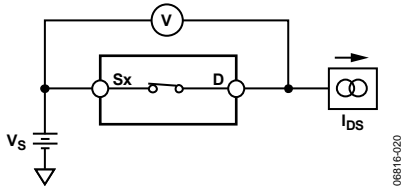


Figure 22. On Resistance

06816-020

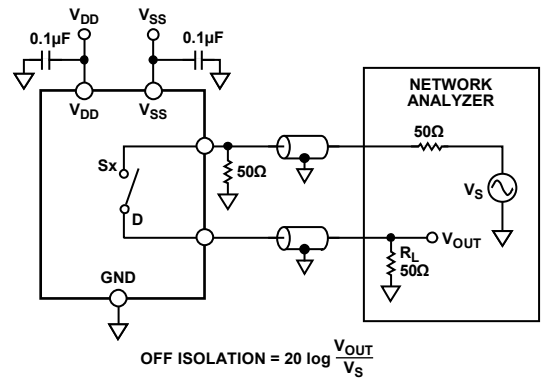


Figure 25. Off Isolation

06816-027

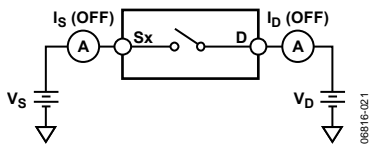


Figure 23. Off Leakage

06816-021

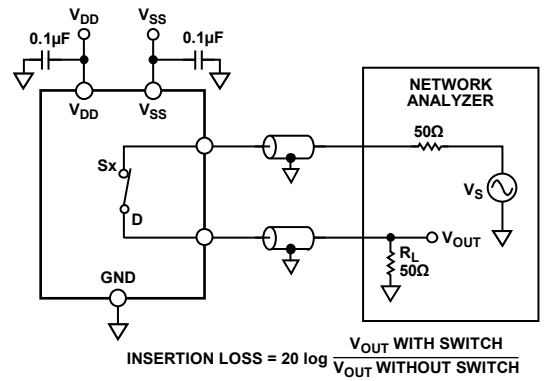


Figure 26. Bandwidth

06816-028

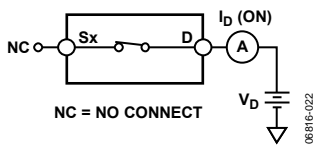


Figure 24. On Leakage

06816-022

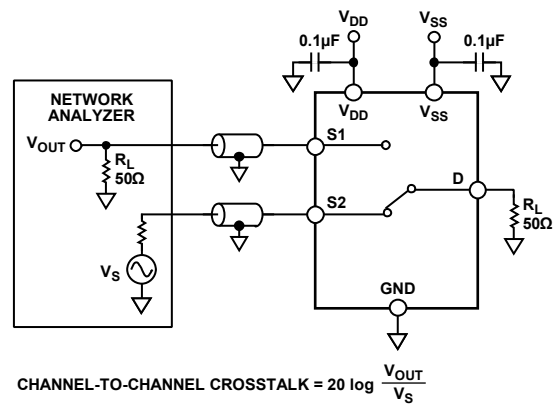


Figure 27. Channel-to-Channel Crosstalk

06816-029

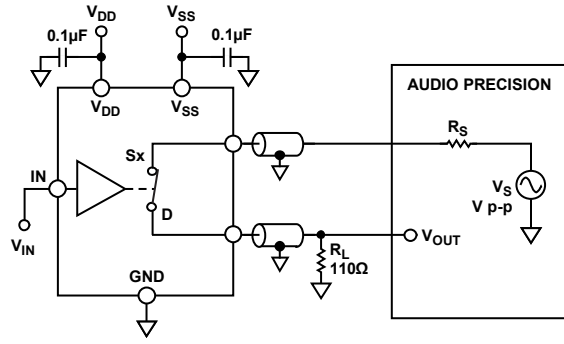


Figure 28. THD + Noise

06816-030

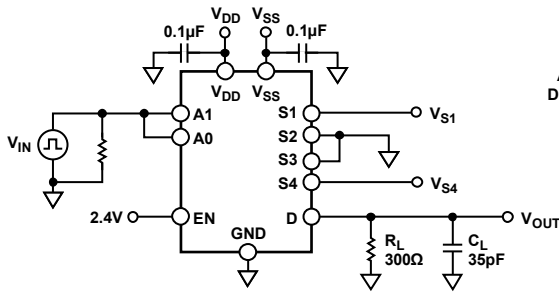


Figure 29. Address to Output Switching Times

06816-023

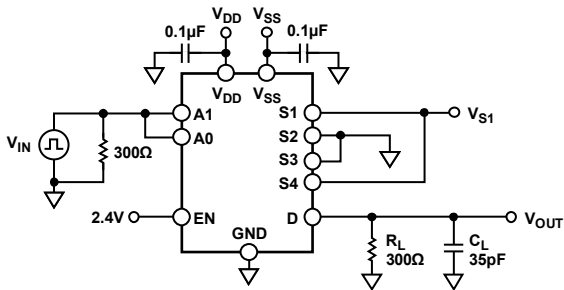


Figure 30. Break-Before-Make Time Delay

06816-024

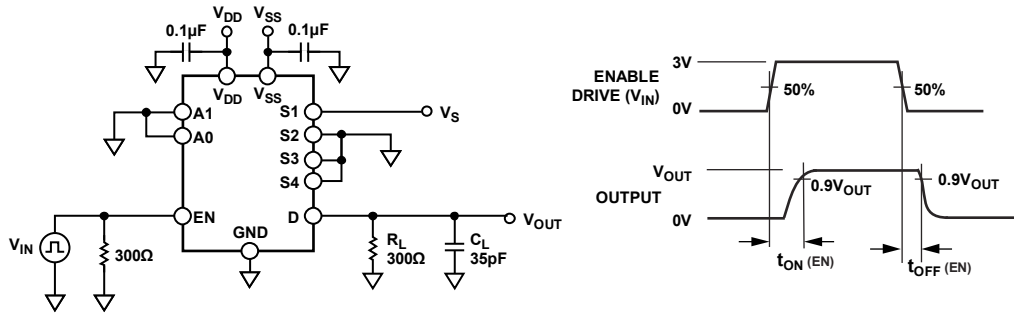


Figure 31. Enable-to-Output Switching Delay

08816-025

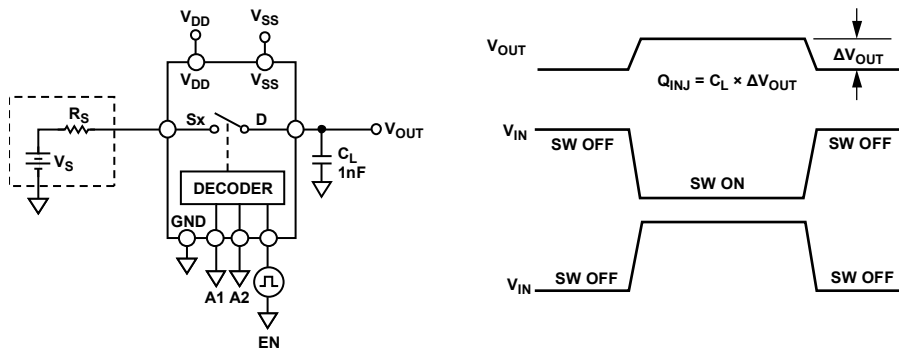
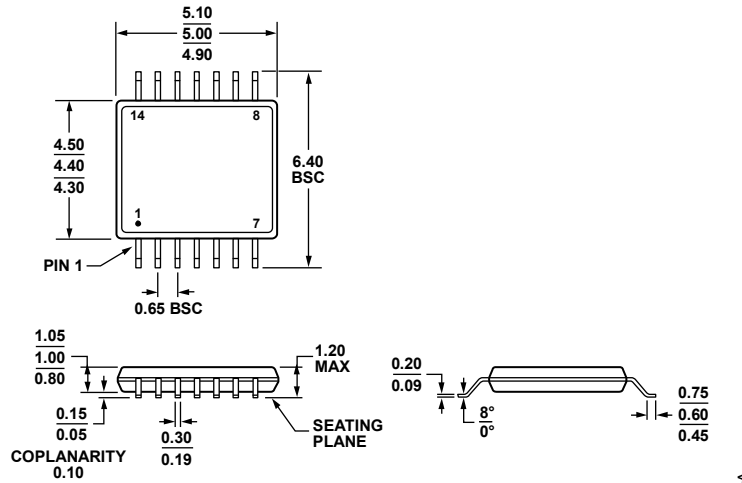


Figure 32. Charge Injection

08816-026

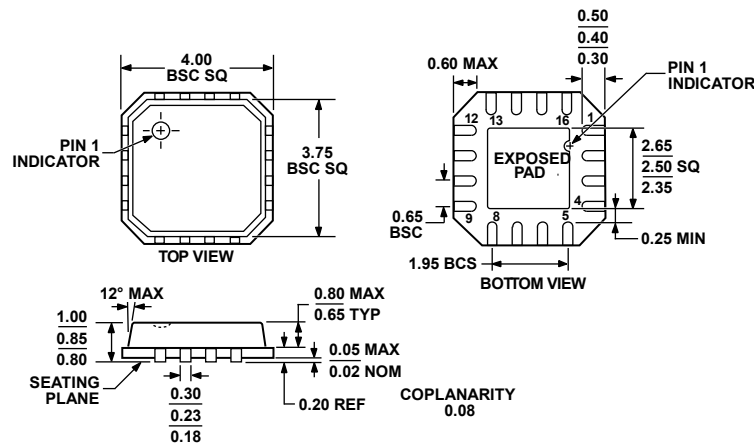
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

Figure 33. 14-Lead Thin Shrink Small Outline Package [TSSOP] (RU-14)

Dimension shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-220-VGGC.

Figure 34. 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ] 4 mm × 4 mm Body, Very Thin Quad

(CP-16-13)

Dimensions shown in millimeters

ORDERING GUIDE

| Model | Temperature Range | Package Description | Package Option |
|--------------------------------|-------------------|---|----------------|
| ADG1404YRUZ ¹ | -40°C to +125°C | 14-Lead Thin Shrink Small Outline Package (TSSOP) | RU-14 |
| ADG1404YRUZ-REEL7 ¹ | -40°C to +125°C | 14-Lead Thin Shrink Small Outline Package (TSSOP) | RU-14 |
| ADG1404YCPZ-REEL ¹ | -40°C to +125°C | 16-Lead Lead Frame Chip Scale Package (LFCSP_VQ) | CP-16-13 |
| ADG1404YCPZ-REEL7 ¹ | -40°C to +125°C | 16-Lead Lead Frame Chip Scale Package (LFCSP_VQ) | CP-16-13 |

¹ Z = RoHS Compliant Part.